

# LTC3525D-3.3

LOGY 400mA Micropower Synchronous Step-Up DC/DC Converter with Pass Through Mode

## FEATURES

- V<sub>OUT</sub> Connected to V<sub>IN</sub> in Shutdown
- Up to 95% Efficiency
- 0.85V Minimum Input Start-Up Voltage
- Fixed Output Voltage of 3.3V
- Delivers 60mA at 3.3V from a 1V Input, or 140mA at 3.3V from a 1.8V Input
- Burst Mode<sup>®</sup> Operation: I<sub>Q</sub> = 7µA
- V<sub>IN</sub> Range: 0.5V to 4.5V
- Only Three External Components
- V<sub>IN</sub> > V<sub>OUT</sub> Operation
- Antiringing Control
- Short-Circuit and Overtemperature Protection
- Very Low Profile of 1mm
- Tiny 6-Pin SC70 Package

### **APPLICATIONS**

- MP3 Players
- Portable Instruments
- Glucose Meters
- Digital Cameras

# TYPICAL APPLICATION

## DESCRIPTION

The LTC®3525D-3.3 is a high efficiency synchronous stepup DC/DC converter that can start up with an input as low as 0.85V. It offers a compact, high efficiency alternative to charge pumps in single cell or dual cell alkaline or Li-ion applications. Only three small external components are required. The LTC3525D features a fixed output voltage of 3.3V. In shutdown, V<sub>OUT</sub> is connected to V<sub>IN</sub> through the inductor.

The device includes a  $0.5\Omega$  N-channel MOSFET switch and a  $0.8\Omega$  P-channel synchronous rectifier. Peak switch current ranges from 150mA to 400mA, depending on load, providing enhanced efficiency. Quiescent current is an ultralow 7µA, maximizing battery life in portable applications.

Other features include anti-ringing control and thermal shutdown. The LTC3525D is available in a tiny 6-pin SC70 package.

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## **ABSOLUTE MAXIMUM RATINGS**

(Note 1)

V <sub>IN</sub> , V <sub>OUT</sub> Voltage	–0.3V to 6V
SW Voltage	-0.3V to 6V
SW Voltage < 100ns	-0.3V to 7V
SHDN Voltage	-0.3V to 6V
Operating Temperature Range	
(Notes 2, 5)–4	10°C to 85°C
Storage Temperature Range65	5°C to 125°C
Lead Temperature (Soldering, 10 sec)	300°C

# PACKAGE/ORDER INFORMATION



Consult LTC Marketing for parts specified with wider operating temperature ranges.

## **ELECTRICAL CHARACTERISTICS**

The  $\bullet$  denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T<sub>A</sub> = 25°C. V<sub>IN</sub> = 1.2V, V<sub>SHDN</sub> = 1.2V, V<sub>OUT</sub> = 3.3V unless otherwise noted.

PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
Input Start-Up Voltage				0.85	1	V
Output Voltage	(Note 6)	•	3.20	3.30	3.40	V
Quiescent Current, V <sub>OUT</sub>	$\overline{\text{SHDN}} = V_{\text{IN}} \text{ (Note 4)}$			7	15	μA
Quiescent Current, V <sub>IN</sub>	SHDN = V <sub>IN</sub> (Note 4)			0.5	3	μA
Quiescent Current, V <sub>IN</sub> - Shutdown	SHDN= 0V, V <sub>OUT</sub> = V <sub>IN</sub> = 3.3VIncluding Switch Leakage			3	10	μA
NMOS Switch On Resistance	(Note 3)			0.5		Ω
PMOS Switch On Resistance	(Note 3)			0.8		Ω
Peak Current Limit			0.4	0.45		A
SHDN Threshold			0.4	0.6	1	V
SHDN Input Current	$V_{\overline{SHDN}} = V_{IN} \text{ or } V_{OUT}$			0.01	1	μA

**Note 1:** Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

**Note 2:** The LTC3525DE is guaranteed to meet performance specifications from 0°C to 85°C. Specifications over the -40°C to 85°C operating temperature range are assured by design, characterization and correlation with statistical process controls.

**Note 3:** Specification is guaranteed by design and not 100% tested in production.

**Note 4:** Current Measurements are performed when the LTC3525D is not switching.

**Note 5:** This IC includes overtemperature protection that is intended to protect the device during momentary overload conditions. Junction temperature will exceed 125°C when overtemperature protection is active. Continuous operation above the specified maximum operating junction temperature may impair device reliability.

**Note 6:** Consult LTC Marketing for other output voltage options.





## **TYPICAL PERFORMANCE CHARACTERISTICS** T<sub>A</sub> = 25°C unless otherwise noted.







 $C_{OUT} = 22\mu F$ 

2.0

1.5

 $V_{IN}(V)$ 

2.5

3.0

3525 G02

3525 G06





**Light Load Burst Frequency** vs Load 40 35 BURST FREQUENCY (KHZ) 30 25 20  $C_{OUT} = 10 \mu F$ 15 10  $C_{OUT} = 22\mu F$ 5 0 0.1 10 1 LOAD (mA) 3525 G12

 $V_{\text{OUT}}$  Variation vs Temperature (Normalized to 25°C)

40 50 60 70 80

LOAD (mA)



Start-Up Delay Coming Out of Shutdown





# **TYPICAL PERFORMANCE CHARACTERISTICS** $T_A = 25^{\circ}C$ unless otherwise noted.



















### PIN FUNCTIONS

**SHDN** (Pin 1): Logic Controlled Shutdown Input. Connect to a voltage >1V to enable the LTC3525D. Connect to a voltage <0.4V to disable the LTC3525D and connect  $V_{IN}$  to  $V_{OUT}$  through the inductor.

### GND (Pins 2, 5): Ground.

 $V_{IN}$  (Pin 3): Input Voltage. The LTC3525D is powered from  $V_{IN}$  until  $V_{OUT}$  exceeds  $V_{IN}$ . Once  $V_{OUT}$  is greater than ( $V_{IN}$  + 0.2V typical), it is powered from  $V_{OUT}$ . Place a ceramic bypass capacitor from  $V_{IN}$  to GND. A minimum value of 1µF is recommended.

 $V_{OUT}$  (Pin 4): Output Voltage Sense and the Output of the Synchronous Rectifier. Connect the output filter capacitor from  $V_{OUT}$  to GND, close to the IC. A minimum value of 10µF ceramic is recommended. Use 22µF for reduced output ripple. The pass-through mode feature connects  $V_{OUT}$  to  $V_{IN}$  through the inductor when SHDN is <0.4V.

**SW (Pin 6):** Switch Pin. Connect an inductor from this pin to  $V_{IN}$ . An internal antiringing resistor is connected across SW and  $V_{IN}$  after the inductor current has dropped to zero to minimize EMI.



# **BLOCK DIAGRAM**



The LTC3525D is a high performance Burst Mode operation only, synchronous boost converter requiring only three small external components. Its simplicity and small size make it a high efficiency alternative to charge pump designs. It is designed to start-up from a single alkaline or nickel cell, with input voltages as low as 0.85V, or from two or three cells (or a Li-ion battery), with voltages as high as 4.5V. Once started, V<sub>IN</sub> can be as low as 0.5V (depending on load current) and maintain regulation. The output voltage is preset internally to 3.3V. Peak switch current is 400mA minimum, providing regulation with load currents up to 150mA, depending on input voltage.

Synchronous rectification provides high efficiency operation while eliminating the need for an external Schottky diode.

The LTC3525D can maintain regulation with an input voltage equal to or greater than  $V_{OUT}$ . Note, however, that the synchronous rectifier is not enabled in this mode, resulting in lower efficiency and reduced output current capability.

The operating quiescent current is only  $7\mu$ A typical, allowing the converter to maintain high efficiency at extremely light loads.

### Shutdown

The LTC3525D is shut down by pulling SHDN below 0.4V, and made active by raising it above 1V. Note that SHDN can be driven as high as 6V, however, if it is more than 0.9V above the higher of  $V_{IN}$  or  $V_{OUT}$ , the SHDN input current will increase from zero to 1.5µA.

After the  $\overline{\text{SHDN}}$  pin rises, there is a short delay before switching starts. The delay is 20µs to 120µs, depending on input voltage (see Typical Performance Characteristics curve).

### **Pass-Through Mode**

When the LTC3525D is in shutdown, the internal P channel MOSFET switch is turned on. This allows  $V_{\text{IN}}$  to be connected to  $V_{\text{OUT}}$  through the inductor in shutdown, creating a pass-through mode.

### Start-up

A start-up oscillator allows the LTC3525D to start with input voltages as low as 1V. It remains in start-up mode until two conditions are met.  $V_{OUT}$  must exceed  $V_{IN}$  by at least 0.2V typical and either  $V_{IN}$  or  $V_{OUT}$  must be greater than 1.8V typical.

During startup, the synchronous rectifier is not enabled, and the internal P-channel synchronous rectifier acts as a follower, causing the peak voltage on SW to reach ( $V_{IN}$ + 1V) typical. This limits inrush current by maintaining control of the inductor current when  $V_{OUT}$  is less than  $V_{IN}$ . To reduce power dissipation in the P-channel synchronous rectifier when the output is shorted, a foldback feature is incorporated that reduces the peak inductor current when  $V_{IN}$  is more than 1.7V greater than  $V_{OUT}$ .







Figure 1. Inductor Current Changing as a Function of Load

#### **Normal Operation**

Once  $V_{OUT}$  has increased more than 0.2V typical above V<sub>IN</sub>, and either voltage is above 1.8V, normal operation begins, with synchronous rectification enabled. In this mode, the internal N-channel MOSFET connected between SW and GND stays on until the inductor current reaches a maximum peak value, after which it is turned off and the P-channel synchronous rectifier is turned on. It stays on, delivering current to the output, until the inductor current has dropped below a minimum value at which point it turns off and the cycle repeats. When the output voltage reaches its regulated value both switches are turned off and the LTC3525D goes to sleep, during which time the output capacitor supplies current to the load. Once the output voltage drops approximately 9mV below the regulation value the IC leaves sleep mode and switching is resumed.

The LTC3525D has been designed for low output voltage ripple. The output voltage ripple is typically only 20mV peak-to-peak at light load and 60mV peak-to-peak at full load using the minimum recommended  $10\mu$ F output capacitor. An anti-ring circuit damps any oscillation at the switch node when the inductor current falls to zero.

#### **Power Adjust Feature**

The LTC3525D incorporates a feature that maximizes efficiency at light load while providing increased power capability at heavy load by adjusting the peak and valley of the inductor current as a function of load. Lowering the peak inductor current to 150mA at light load optimizes efficiency by reducing conduction losses in the internal MOSFET switches. As the load increases, the peak inductor current is automatically increased to a maximum of 400mA. At intermediate loads, the peak inductor current may vary from 150mA to 400mA. Figure 1 shows an example of how the inductor current changes as the load increases. Please note that output capacitor values greater than  $47\mu$ F will result in higher peak currents than necessary at light load. This will lower the light load efficiency.

The valley of the inductor current is automatically adjusted as well, to maintain a relatively constant inductor ripple current. This keeps the switching frequency relatively constant.



The maximum average load current that can be supported is given by:

$$I_{O(MAX)} = \frac{0.3 \bullet V_{IN} \bullet \eta}{V_0} Amps$$

Where  $\eta$  is the efficiency (see Typical Performance Characteristics).

The "burst" frequency (how often the LTC3525D delivers a burst of current pulses to the load) is determined by the internal hysteresis (output voltage ripple), the load current and the amount of output capacitance. All Burst Mode operation or hysteretic converters will enter the audible frequency range when the load is light enough. However, due to the low peak inductor current at light load, circuits using the LTC3525D do not typically generate any audible noise.

### **Component Selection**

Inductor values between  $4.7\mu$ H and  $15\mu$ H are recommended. In most applications  $10\mu$ H will yield the best compromise between size and efficiency. The inductor should be a low-loss ferrite design and must be rated for peak currents of at least 400mA without saturating.

Inductors with lower DC resistance will improve efficiency. Note that the inductor value does not have a significant effect on ripple current, so while lower values will increase the operating frequency, they do not reduce output voltage ripple.

Some recommended inductor examples are Murata LQH32C, Coilcraft LPO4812, LPO3310, DO3314, DS1608 and MSS4020, Sumida CDRH2D14 and Taiyo Yuden NR3015T.

A ceramic input bypass capacitor should be located as close as possible to the V<sub>IN</sub> and GND pins of the IC. A minimum value of  $1\mu$ F is recommended. If the battery is more than a few inches away, a bulk tantalum decoupling cap of at least  $10\mu$ F is recommended on V<sub>IN</sub>.

The output capacitor should also be a ceramic, located close to the  $V_{OUT}$  and GND pins. A minimum value of  $10\mu$ F is recommended. Increasing the value of the output capacitor to  $22\mu$ F will result in lower output ripple. Higher capacitor values will only offer a small reduction in output ripple, while reducing light load efficiency by causing the peak inductor current to increase above its minimum value of 150mA. The input and output capacitors should be X5R or X7R types, not Y5V.



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#### Table 1. Inductor Vendor Information

SUPPLIER	PHONE	FAX	WEBSITE
Murata	USA: (814) 237-1431	USA: (814) 238-0490	www.murata.com
Coilcraft	(847) 639-6400	(847) 639-1469	www.coilcraft.com
Sumida	USA: (847) 956-0666	USA: (847) 956-0702	www.sumida.com
Taiyo Yuden	(408) 573-4150	(408) 573-4159	www.t-yuden.com

#### Table 2. Capacitor Vendor Information

SUPPLIER	PHONE	FAX	WEBSITE
Murata	USA: (814) 237-1431	USA: (814) 238-0490	www.murata.com
Taiyo Yuden	(408) 573-4150	(408) 573-4159	www.t-yuden.com
TDK	(847) 803-6100	(847) 803-6296	www.component.tdk.com
AVX	(803) 448-9411	(803) 448-1943	www.avxcorp.com



Figure 2. Recommended Component Placement



## **TYPICAL APPLICATION**



Single Alkaline or NiMH to 3.3V Converter with 1mm Profile







### PACKAGE DESCRIPTION



SC6 Package 6-Lead Plastic SC70 (Reference LTC DWG # 05-08-1638 Rev B)

BUT MUST BE LOCATED WITHIN THE INDEX AREA

- 7. EIAJ PACKAGE REFERENCE IS EIAJ SC-70
- 8. JEDEC PACKAGE REFERENCE IS MO-203 VARIATION AB



## **RELATED PARTS**

PART NUMBER	DESCRIPTION	COMMENTS
LT <sup>®</sup> 1615/LT1615-1	300mA/80mA (I <sub>SW</sub> ), High Efficiency Step-Up DC/DC Converter	V <sub>IN</sub> : 1V to 15V, V <sub>OUT(MAX)</sub> = 34V, I <sub>Q</sub> = 20µA, I <sub>SD</sub> <1µA, ThinSOT™ Package
LT1930/LTC1930A	1A (I <sub>SW</sub> ), 1.2MHz/2MHz, High Efficiency Step-Up DC/DC Converter	High Efficiency, V <sub>IN</sub> : 2.6V to 16V, V <sub>OUT(MAX)</sub> = 34V, $I_Q = 4.2mA/5.5mA$ , $I_{SD} < 1\muA$ , ThinSOT Package
LTC3400/LTC3400B	600mA (I <sub>SW</sub> ), 1.2MHz, Synchronous Step-Up DC/DC Converter	92% Efficiency, V <sub>IN</sub> : 0.5V to 5V, V <sub>OUT(MAX)</sub> = 5V, $I_Q = 19\mu A/300\mu A$ , $I_{SD} < 1\mu A$ , ThinSOT Package
LTC3401	1A (I <sub>SW</sub> ), 3MHz, Synchronous Step-Up DC/DC Converter	97% Efficiency, V <sub>IN</sub> : 0.5V to 5V, V <sub>OUT(MAX)</sub> = 5.5V, I <sub>Q</sub> = 38 $\mu$ A, I <sub>SD</sub> <1 $\mu$ A, MS Package
LTC3402	2A (I <sub>SW</sub> ), 3MHz, Synchronous Step-Up DC/DC Converter	97% Efficiency, V <sub>IN</sub> : 0.5V to 5V, V <sub>OUT(MAX)</sub> = 5.5V, I <sub>Q</sub> = 38 $\mu$ A, I <sub>SD</sub> <1 $\mu$ A, MS Package
LTC3421	3A (I <sub>SW</sub> ), 3MHz, Synchronous Step-Up DC/DC Converter with Output Disconnect	95% Efficiency, V <sub>IN</sub> : 0.5V to 4.5V, V <sub>OUT(MAX)</sub> = 5.25V, I <sub>Q</sub> = 12µA, I <sub>SD</sub> <1µA, QFN-24 Package
LTC3429/LTC3429B	600mA, 500kHz Single/Dual Cell Micropower Synchronous Boost Converter with Output Disconnect	95% Efficiency, V <sub>IN</sub> : 1V to 4.5V, V <sub>OUT(MAX)</sub> = 5V, $I_Q$ = 20µA, $I_{SD}$ <1µA, SC70 Package
LTC3458	1.4A (I <sub>SW</sub> ), 1.5MHz, Synchronous Step-Up DC/DC Converter with Output Disconnect	V <sub>IN</sub> : 1.5V to 6V, V <sub>OUT(MAX)</sub> = 7.5V, I <sub>SD</sub> <1µA, 3mm × 4mm DFN Package
LTC3458L	1.7A (I <sub>SW</sub> ), 1.5MHz, Synchronous Step-Up DC/DC Converter with Output Disconnect	V <sub>IN</sub> : 1.5V to 6V, V <sub>OUT(MAX)</sub> = 6V, I <sub>SD</sub> <1µA, 3mm × 4mm DFN Package
LTC3459	60mA, 10V Micro Power Synchronous Boost Converter	95% Efficiency, V <sub>IN</sub> : 1.5V to 6V, V <sub>OUT(MAX)</sub> = 10V, $I_Q$ =10µA, $I_{SD}$ <1µA, ThinSOT Package
LT3464	85mA (I <sub>SW</sub> ), High Efficiency Step-Up DC/DC Converter with Integrated Schottky and PNP Disconnect	$V_{IN}$ : 2.3V to 10V, $V_{OUT(MAX)}$ = 34V, $I_Q$ = 25µA, $I_{SD}$ <1µA, ThinSOT Package
LT3427	500mA (I <sub>SW</sub> ), 1.2MHz, Step-Up DC/DC Converter with Output Disconnect	V <sub>IN</sub> : 1.8V to 5V, V <sub>OUT(MAX)</sub> = 5V, I <sub>SD</sub> <1µA, 2mm × 2mm DFN Package
LTC3525-3/LTC3525-3.3/ LTC3525-5	400mA Synchronous Step-Up DC/DC Converter with Output Disconnect	$V_{IN}$ : 0.5V to 4.5V, $V_{OUT(MAX)}$ = 5V, $I_Q$ = 7µA, $I_{SD}$ <1µA, SC70 Package
LTC3526/LTC3526B	500mA. 1MHz, Synchronous Step-Up DC/DC Converter with Output Disconnect	$V_{\text{IN}}$ : 0.5V to 4.5V, $V_{\text{OUT}(\text{MAX})}$ = 5.25V, $I_{\text{Q}}$ = 9µA, $I_{\text{SD}}$ <1µA, 2mm × 2mm DFN-6 Package

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